

High-Contrast, All-Optical Switching of Infrared Light using a Cadmium Oxide Perfect Absorber

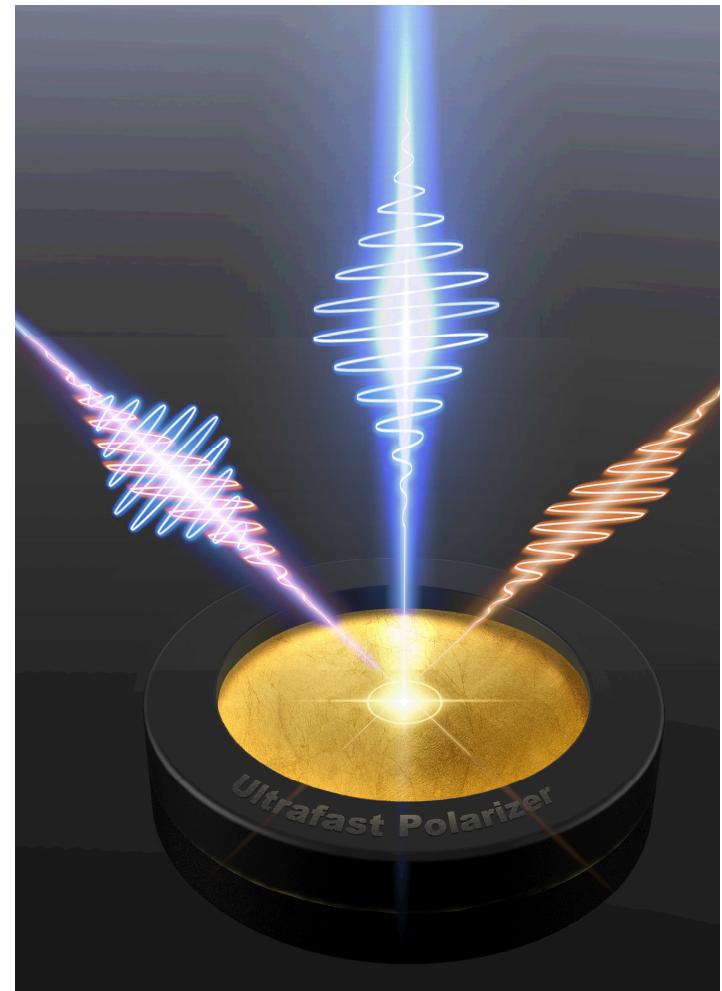
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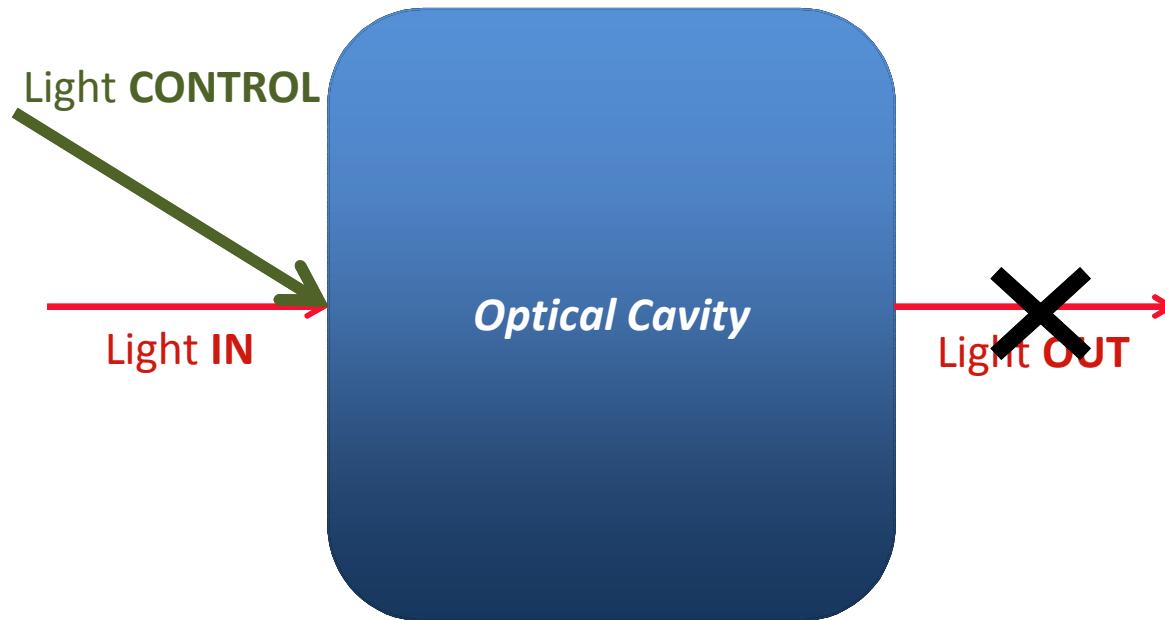
yuayang@sandia.gov

CLEO, San Jose, CA
May 15th, 2017



All-optical switching:

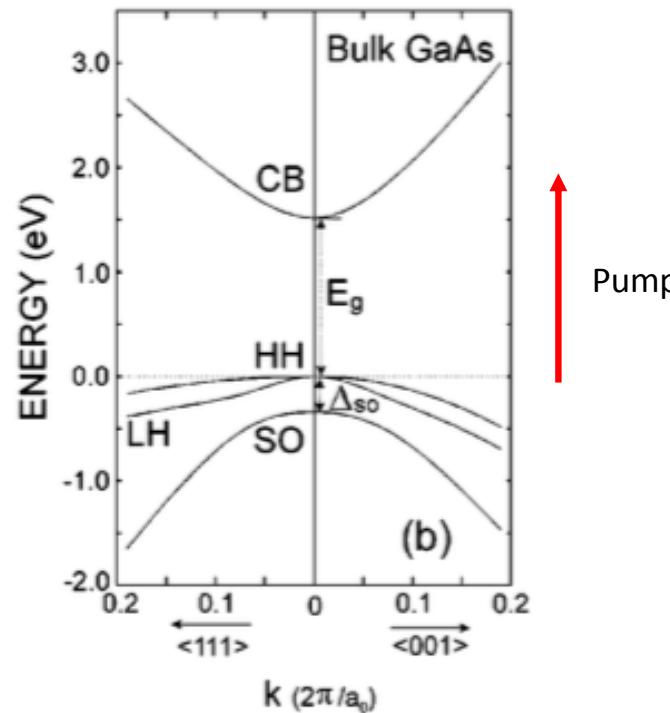
- **Photon** as the *control*.
- **Photon** as the *signal*.



Metrics:

- Fast Switching Speed
- Large Switching Contrast
- Small Form Factor
- Low Power Consumption

Photon-“create” electrons:



Vurgaftmana JAPN (2001)

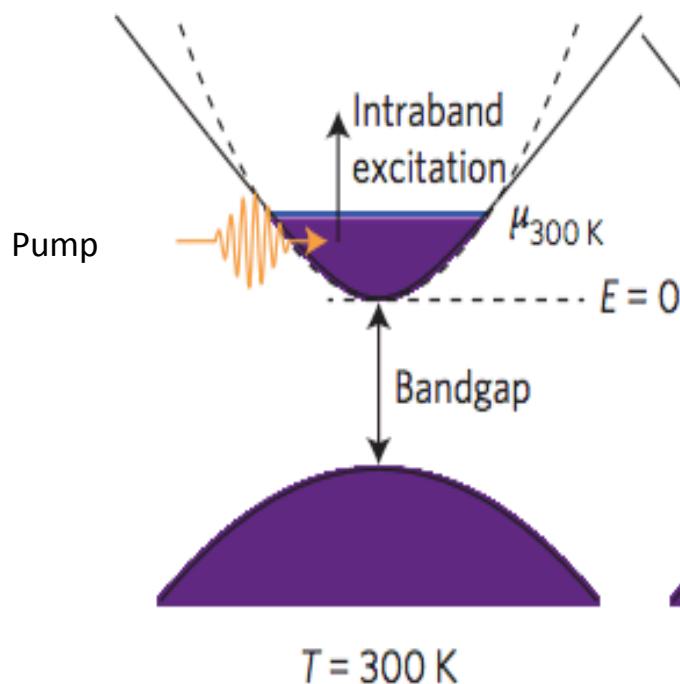
Plasma frequency:

$$\omega_p = \sqrt{n e^2 / \epsilon_0 m^*}$$

Speed limitations:

- Carrier lifetime

Photon-“perturb” electrons:



$$m^* = \frac{\hbar^2 \int f(E, T) dk}{\int f(E, T) (d^2 E / dk^2) dk}$$

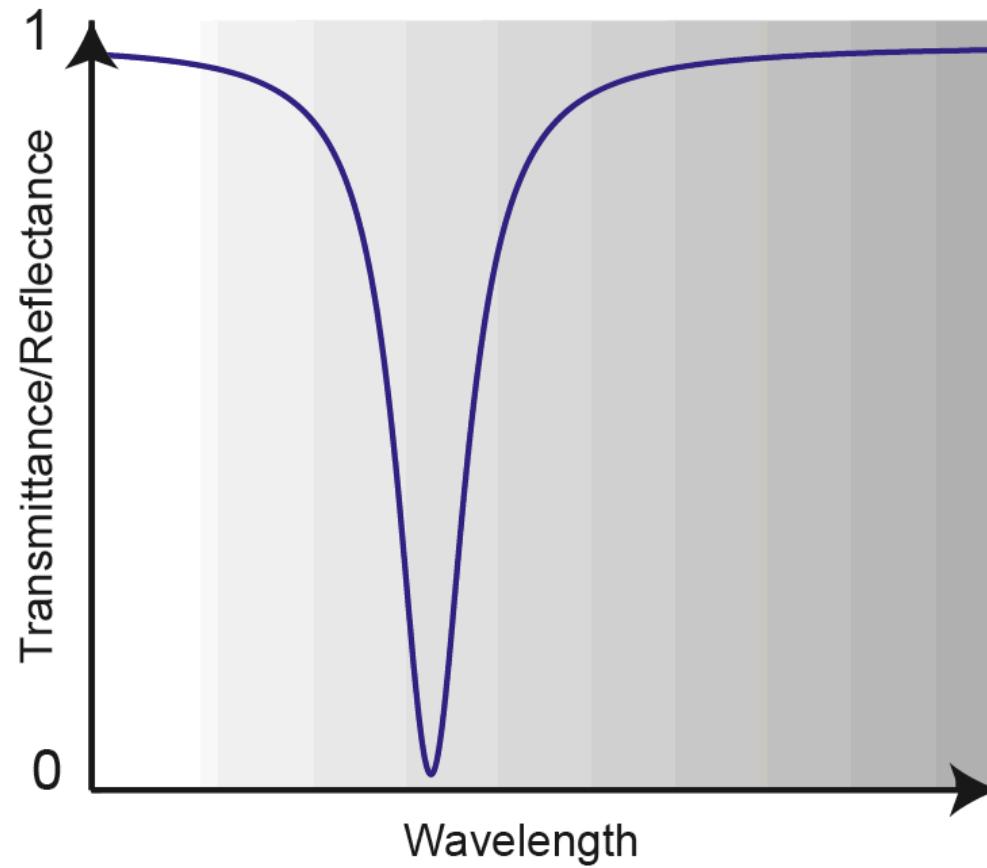
Plasma frequency:

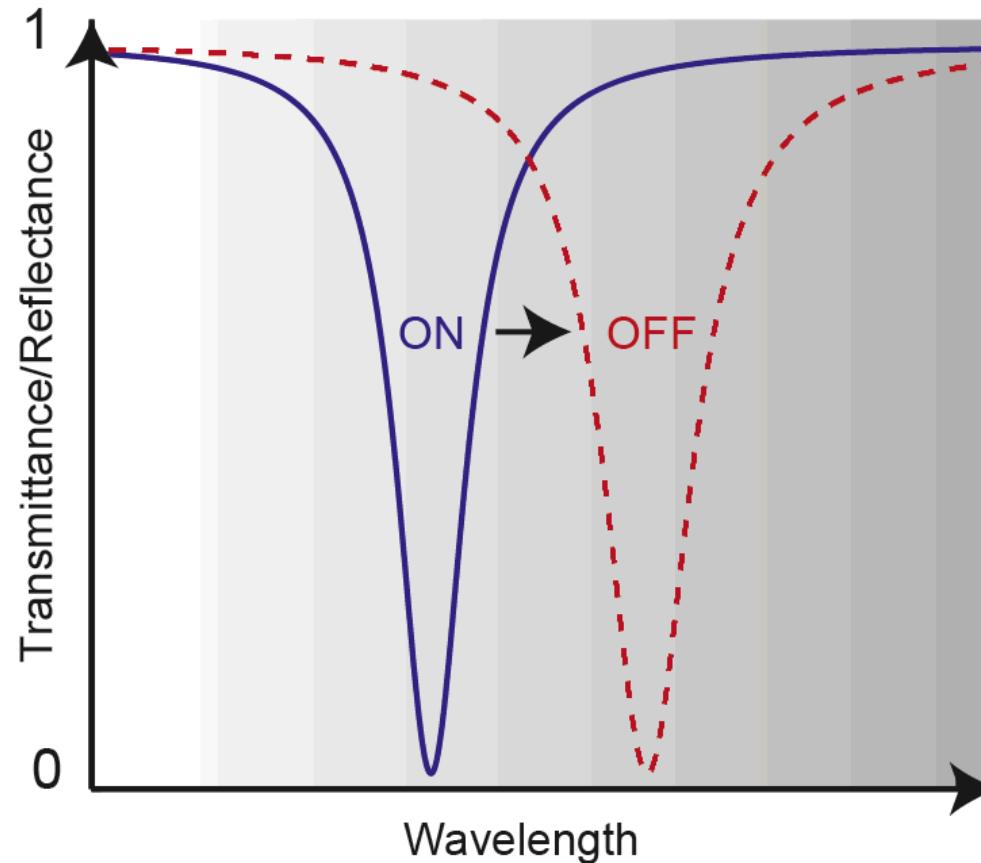
$$\omega_p = \sqrt{n e^2 / \epsilon_0 m^*}$$

Speed limitations:

- Hot carrier lifetime

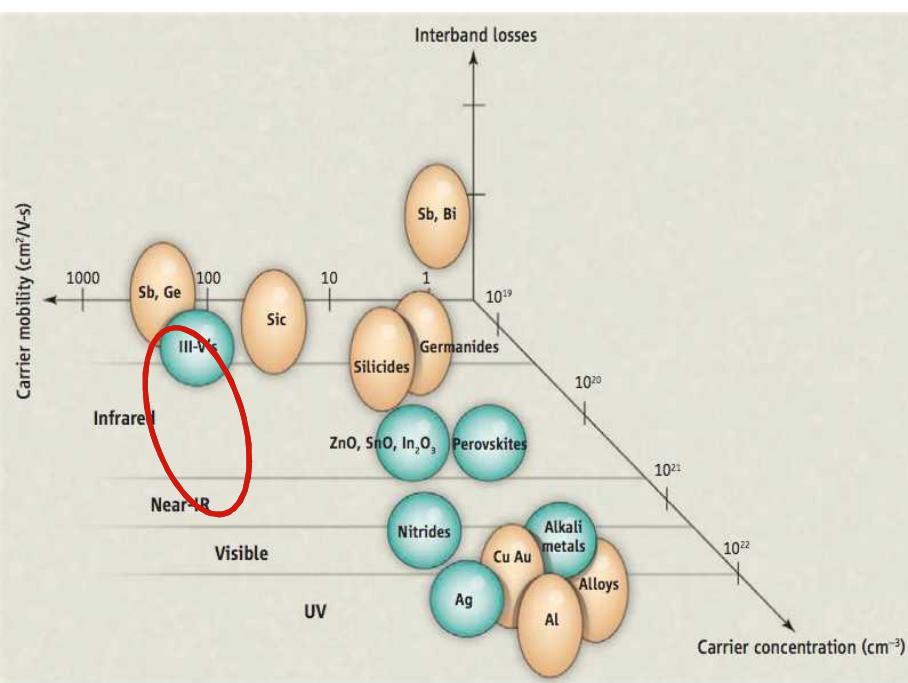
Guo et. al., Nat. Photon, (2016)



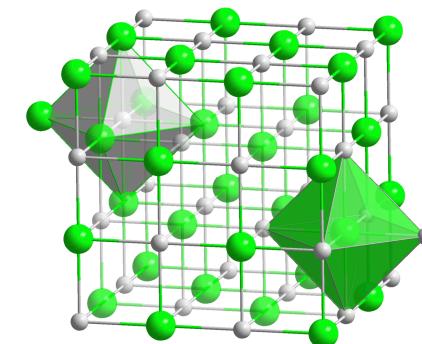


Requirements

- **High quality factor resonance**
 - Low loss plasmonic material
- **Small reflectance minimum**
 - Proper cavity design



Boltasseva & Atwater, Science 331, 290 (2011)



- Cubic rocksalt lattice (similar to NaCl)
- n-doping (In populates the Cd sublattice with a 3+ charge)

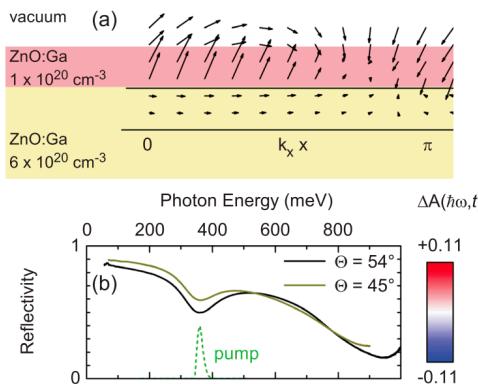
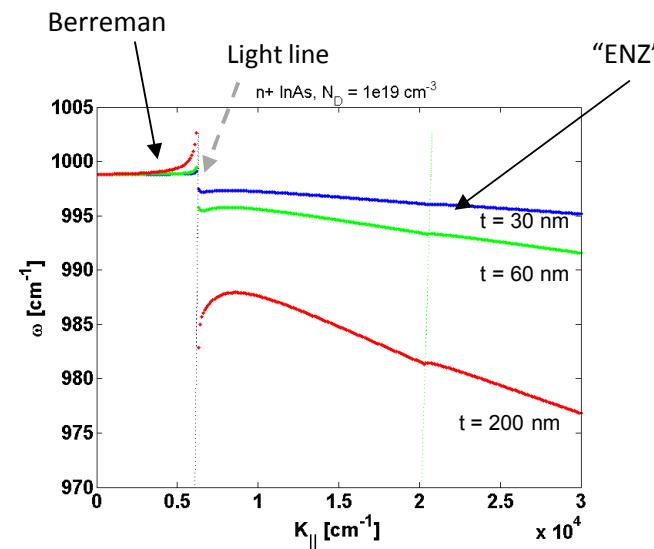
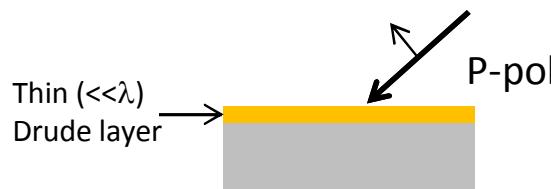
<http://chemistry.stackexchange.com/questions/23673/rock-salt-structure>

- Doping density can reach $> 10^{20} \text{ cm}^{-3}$.
- Plasma frequency tunable from near to mid IR.
- Mobilities in the 100's via accurate defect equilibrium engineering.

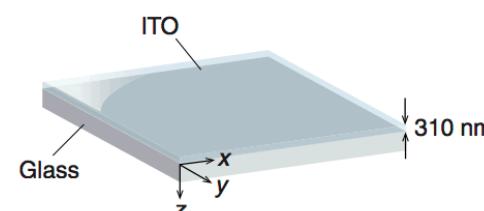
Material	Carriers [cm ⁻³]	Mobility [cm ² /V·s]	$\epsilon_1=0$ [cm ⁻¹]	ϵ_2 at $\epsilon_1=0$	ϵ_2 at $\epsilon_1=-2$
CdO:Dy	9.94×10^{19}	474	2770	0.19	0.30
CdO:Dy	3.70×10^{20}	359	5350	0.13	0.20
AZO (2 wt%) ⁴	7.2×10^{20}	48	6970	0.21	0.39
ITO (10 wt%) ⁴	7.7×10^{20}	36	7122	0.69	1.29

Sachet et. al., Nat. Mat (2015)

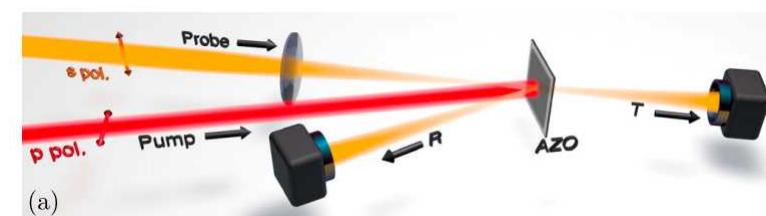
J-P Maria, NC State



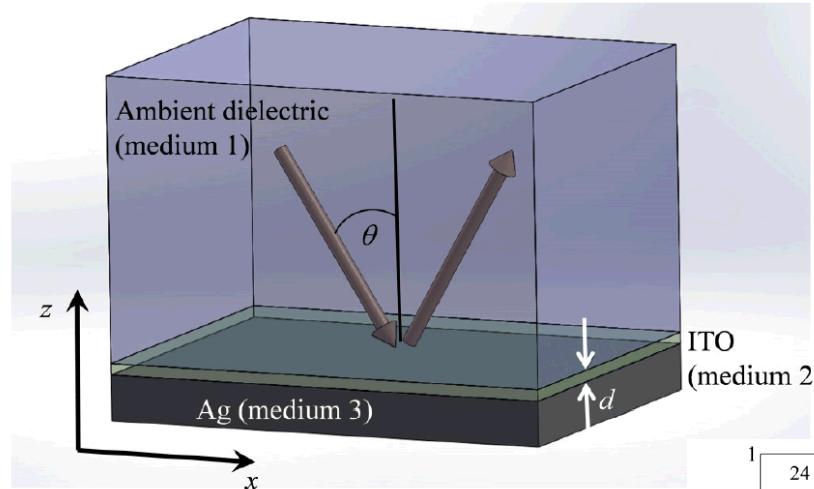
Tyborski et. al., PRL (2015)



Alam et. al., Science (2016)



Caspani et. al., PRL (2016)



PHYSICAL REVIEW B 90, 085411 (2014)

Directional perfect absorption using deep subwavelength low-permittivity films

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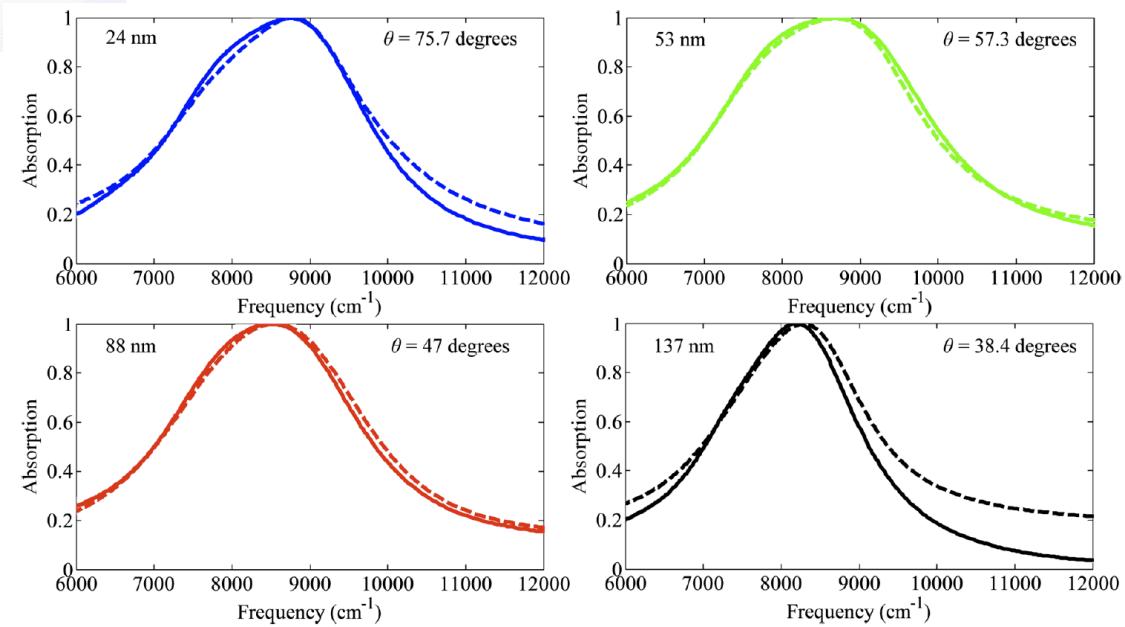
²Center for Integrated Nanotechnologies, Sandia National Laboratories, P.O. Box 5800, Albuquerque, New Mexico 87185, USA

³Naval Surface Warfare Center Dahlgren Division, 18444 Frontage Road, Dahlgren, Virginia 22448, USA

⁴Department of Physics, Inha University, Incheon 402-751, Republic of Korea

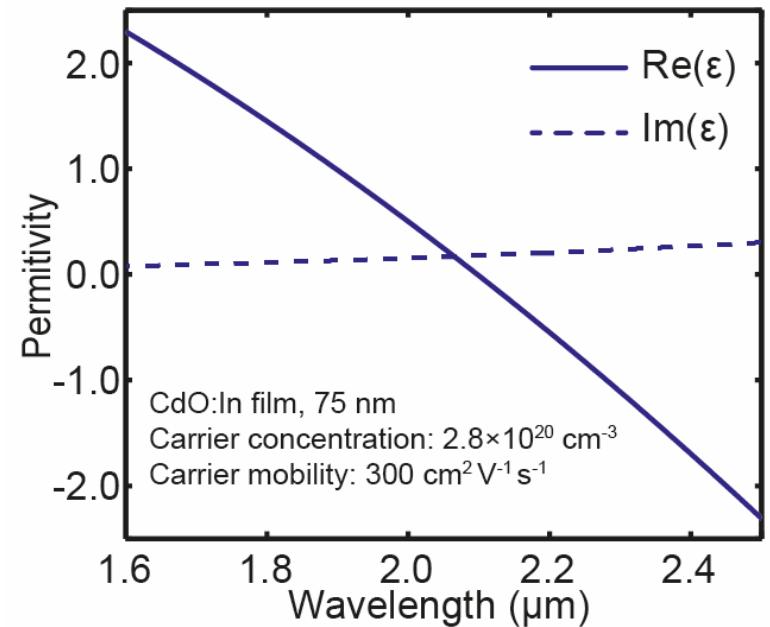
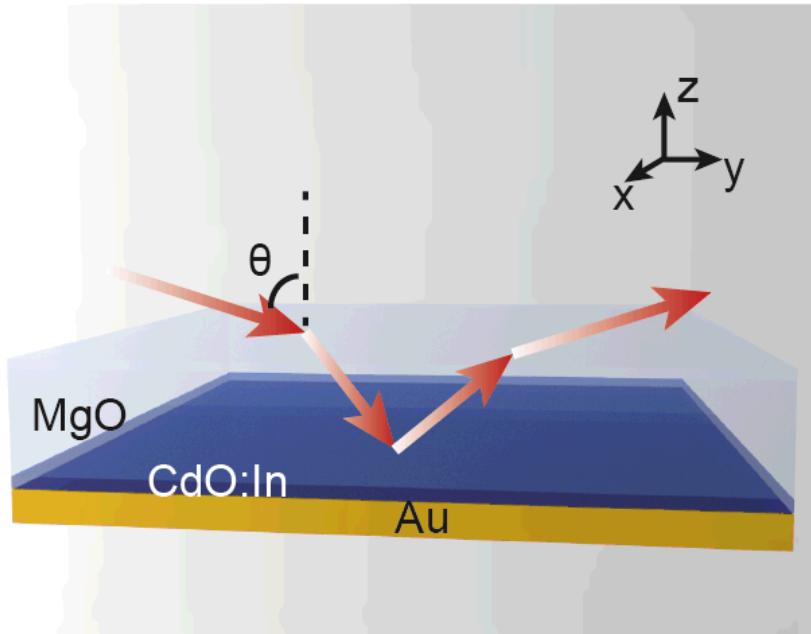
⁵Edward L. Ginzton Laboratory, Stanford University, Stanford, California 94305-4088, USA

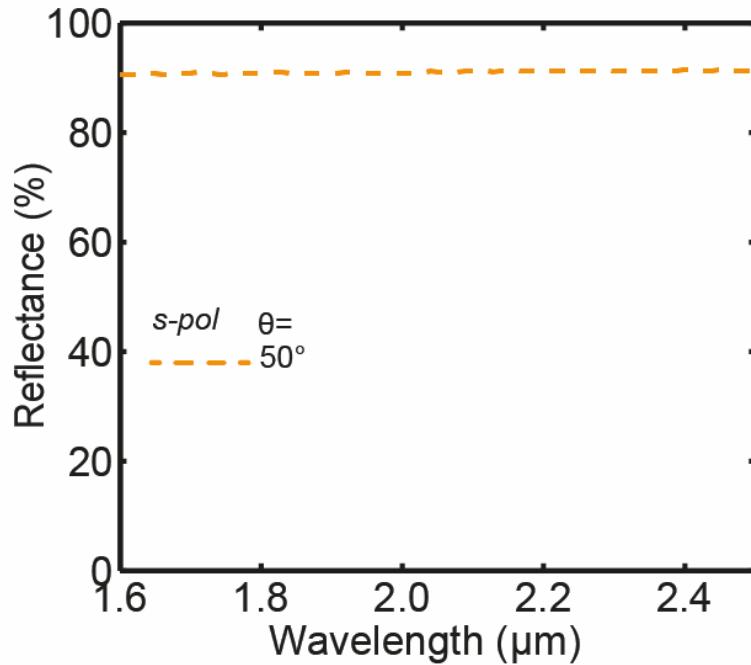
(Received 14 May 2014; published 11 August 2014)

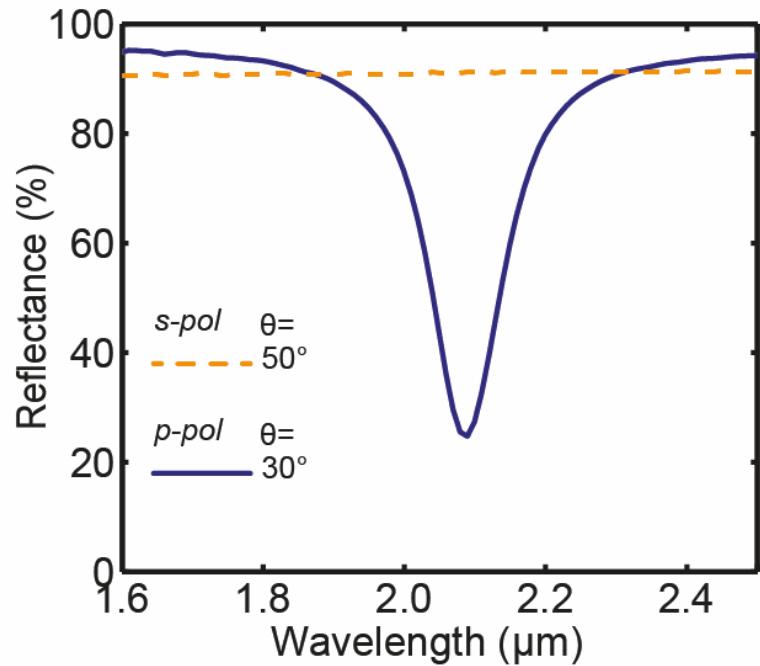


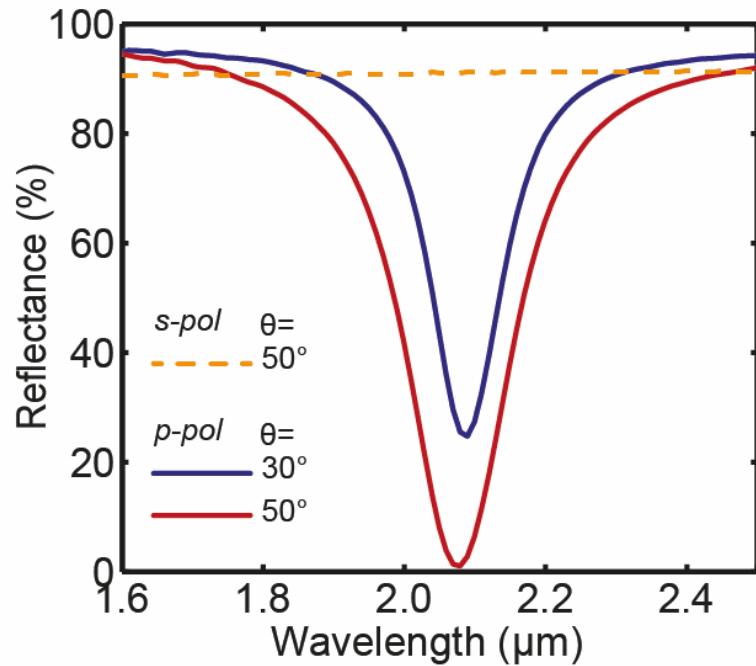
Perfect absorber:

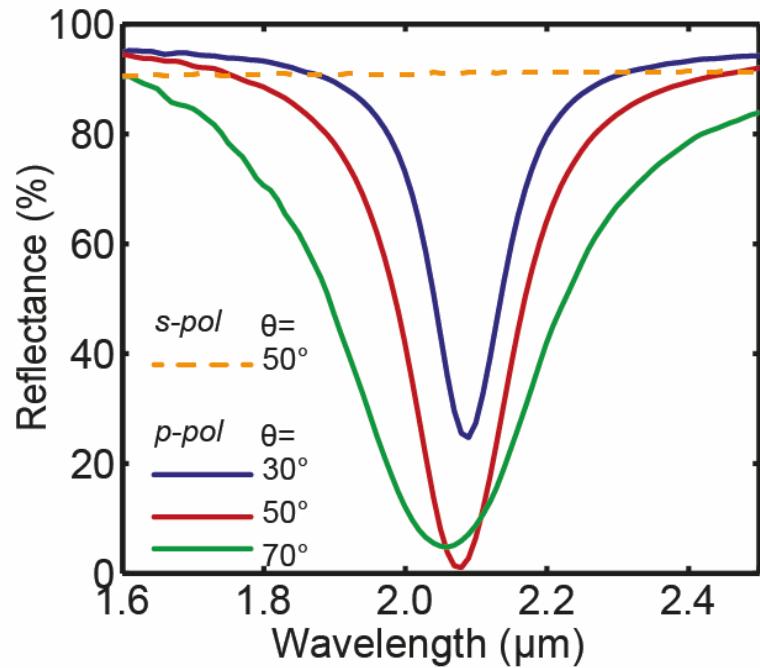
- Small reflectance minimum

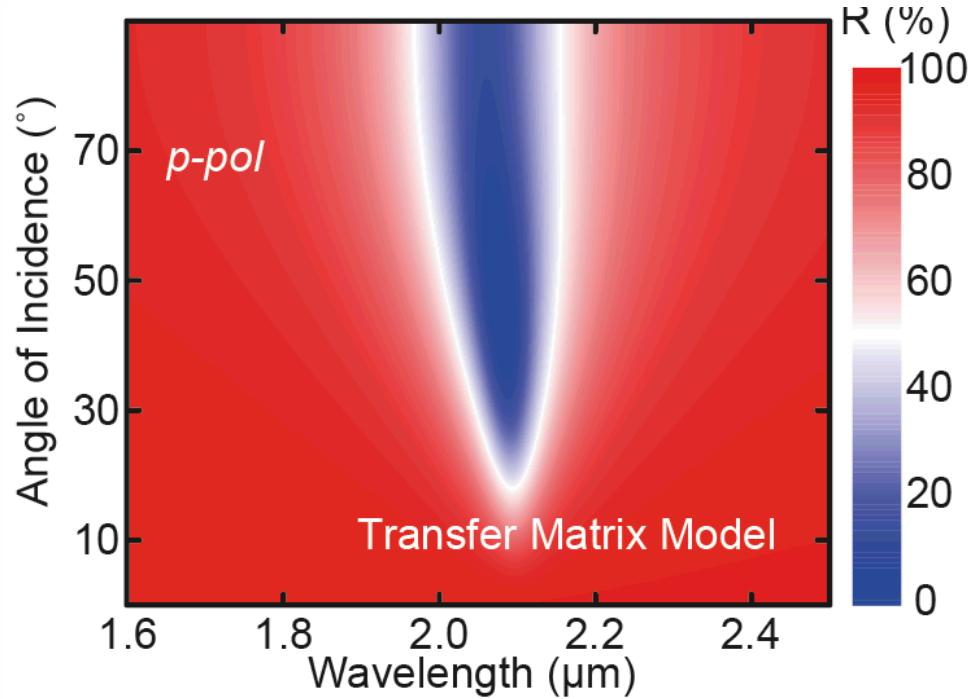
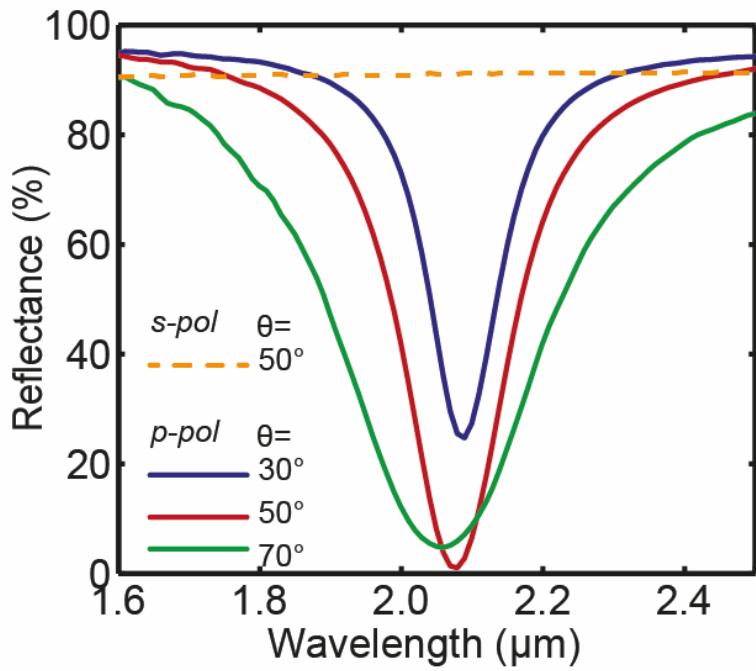


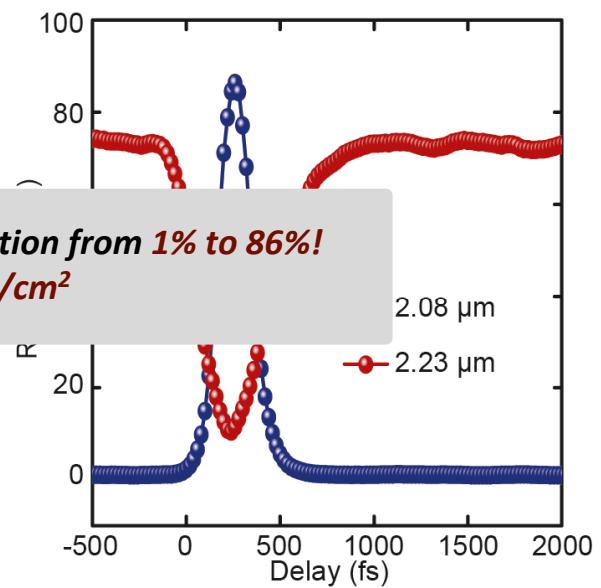
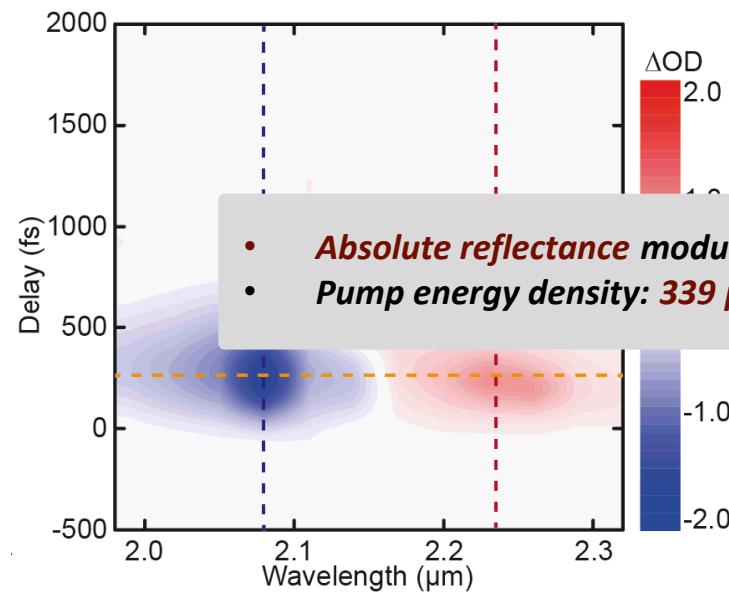
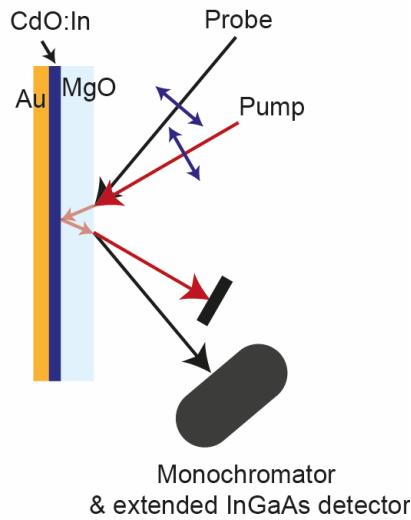


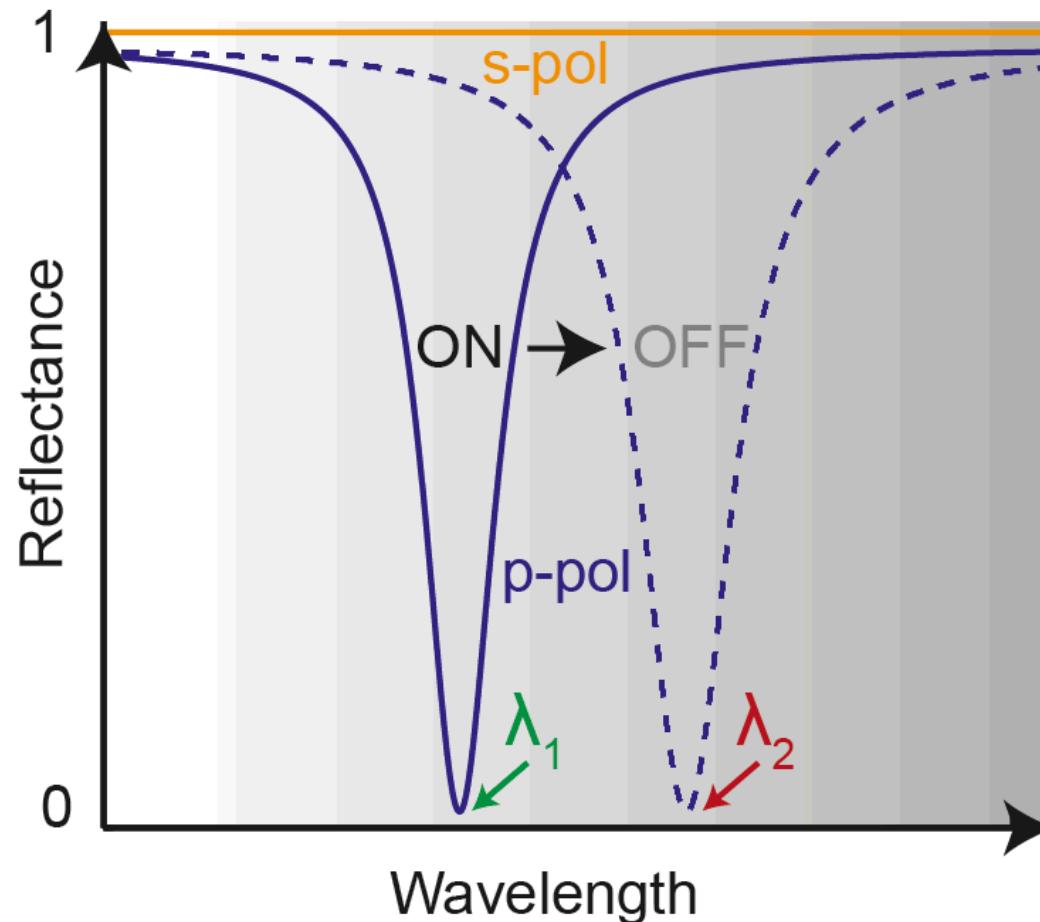


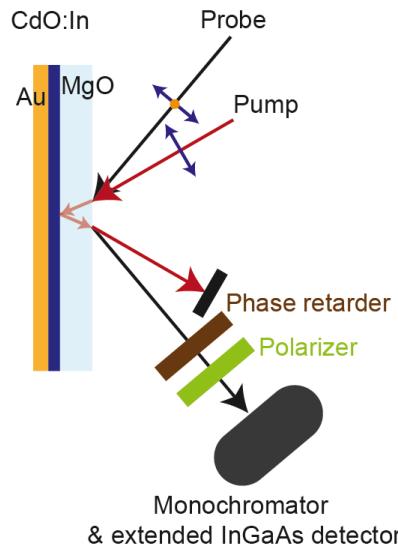




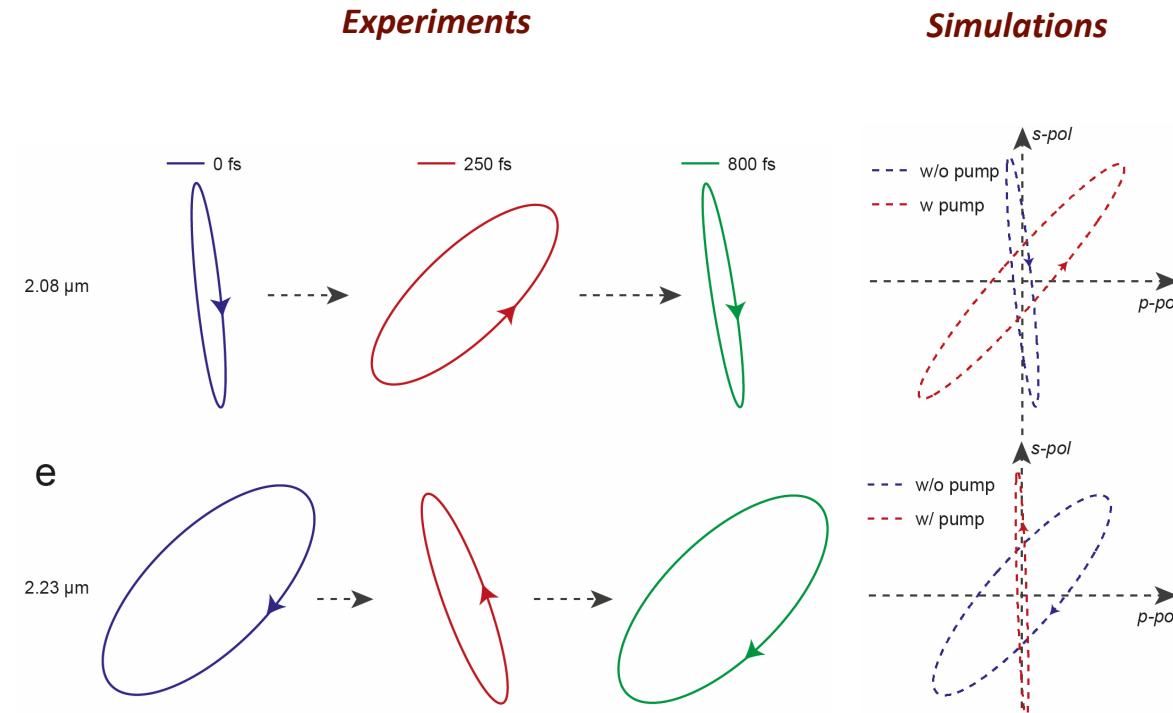
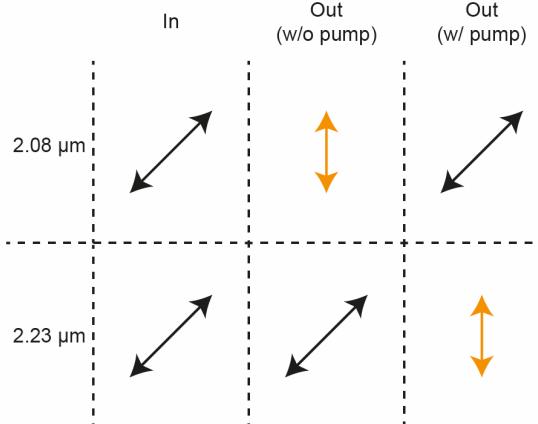








Predicted polarization input/output:



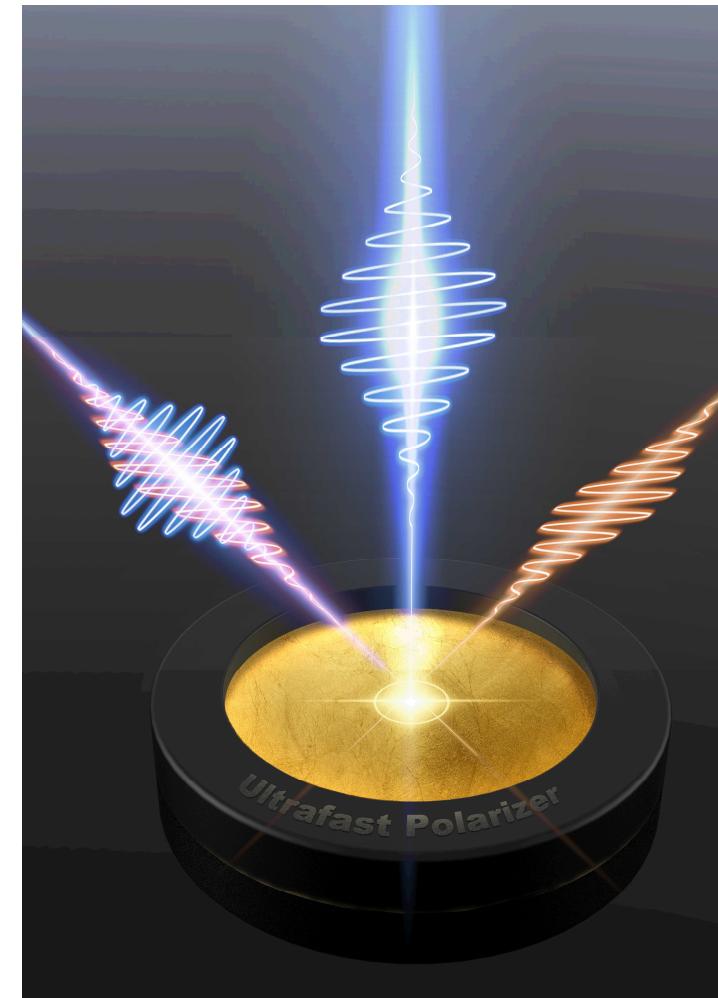
Conclusions

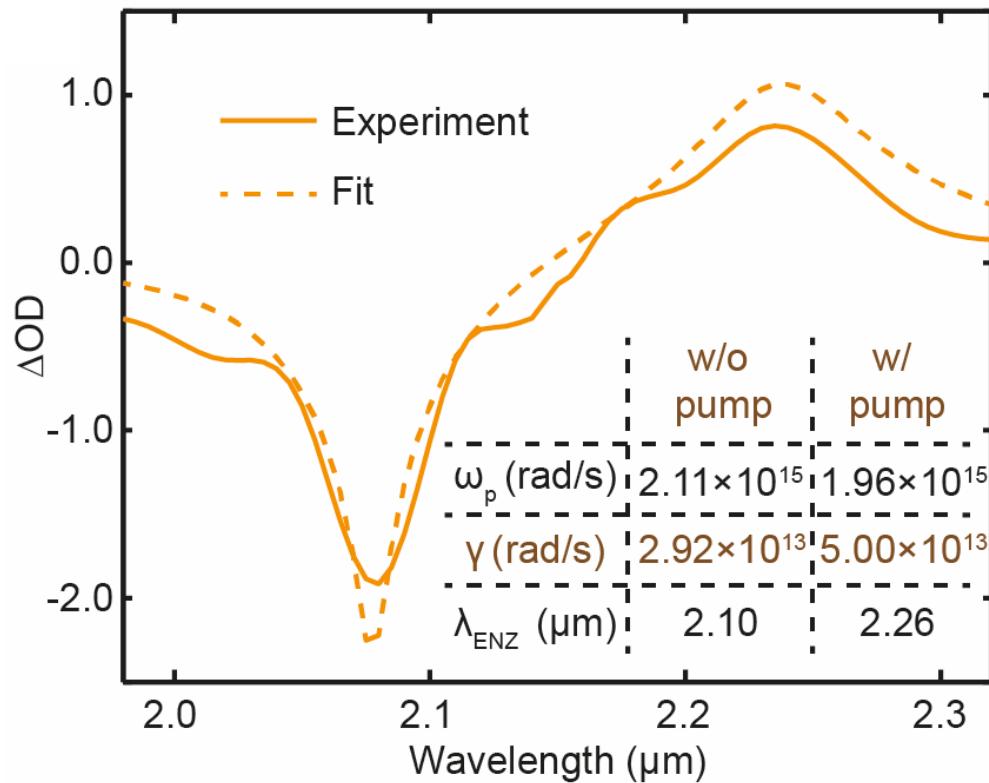
- Ultrafast switches using doped CdO
 - High electron mobility oxide/perfect absorber
 - High contrast amplitude switch
 - Femtosecond polarization switch

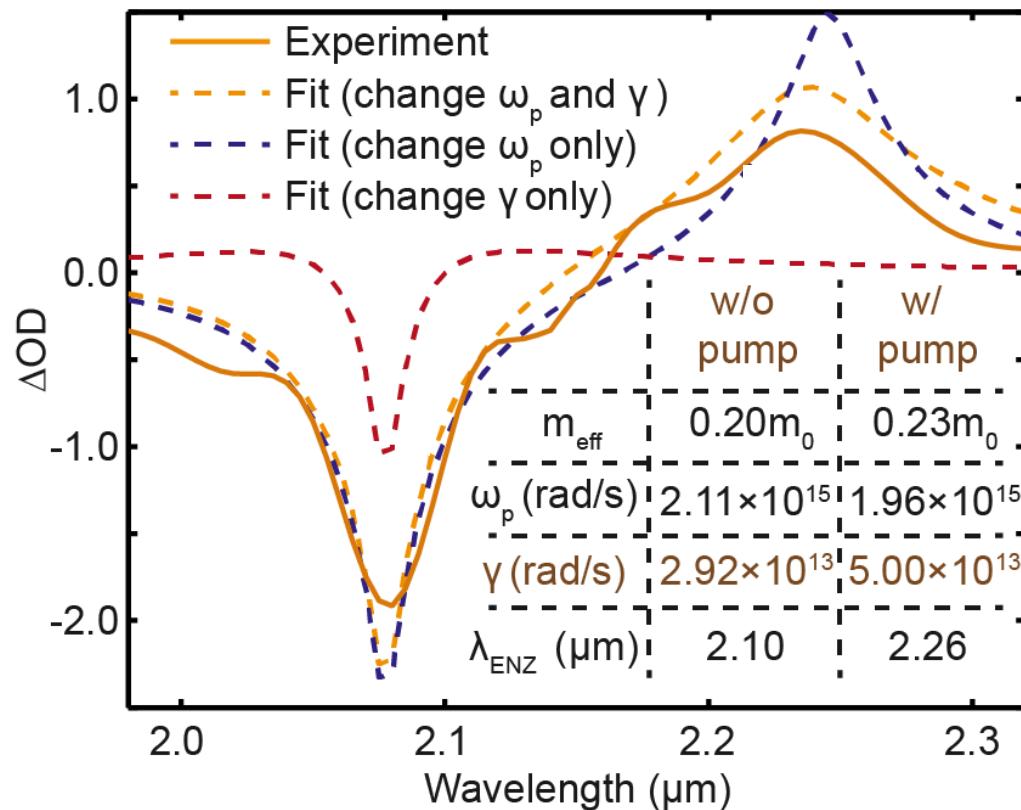
Acknowledgement

- CINT (& Sandia)
 - I. Brener, M.B. Sinclair, S. Campione, S. Liu, T.S. Luk, P.Q. Liu
- North Carolina State
 - J-P. Maria, K. Kelley, E. Sachet

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- Change in **plasma frequency** plays the dominant role.
- Change in **plasma damping** observed.